OFFICE OF THE DEAN (R & C), NIT, TIRUCHI

ADVERTISEMENT FOR RECRUITMENT OF JRF

Ref. No: YS/PD-IP/345

26th April 2022

Applications are invited from eligible Indian Nationals only for the position of Junior Research Fellow for the ISRO-STIC sponsored research project under the principal investigator **Dr.Shelas Sathyan**, **Assistant Professor**, **Department of Electrical and Electronics Engineering**, in **National Institute of Technology**, **Tiruchirappalli-15**, Tamil Nadu. The details of the project are given below.

1.	Title of the Project	Development of Bi-directional Battery Charger- Discharge Regulator (BCDR)
2.	Funding Agency for the Project specimen	Indian Space Research Organisation (ISRO)
3.	Project Positions and Number	JRF and 01 (Electrical-1)
4.	Qualifications	 M.E / M-Tech/MS Specialized in Power Electronics /Power Systems. Minimum 60% or 6.5 CGPA in UG and PG from a recognized University/ Institute. Candidates with qualified GATE score will be given priority. Applicants who have not qualified in GATE/equivalent national level test are also eligible to apply. Selected candidates may have a chance to register for the Ph.D. at NIT Tiruchirappalli.
5.	Salary	Rs. 36,580/- (Rs.31,000/- plus 18% HRA)
6.	Duration	24 Months (Tenure extension based on the performance review for every 12 months)
7.	Job Description	 Purchase of Equipment's and Components. Designing, Simulating and Setting up of the hardware in the laboratory. Evaluate and Analyse the system. Design and Testing of Bi-directional Battery Charger- Discharge Regulator at NIT-T and documentation of results Drafting original manuscript and progress report yearly. Travelling to U R Rao Satellite Centre center Bangalore for technical discussions

- A. Candidates before appearing for the interview shall ensure that they are eligible for the position they intend to apply.
- B. Candidates desiring to appear for the Interview should submit their applications with the following documents to the Office of the Principal Investigator **Dr.Shelas Sathyan**, **Department of Electrical and Electronics Engineering**, **National Institute of Technology Tiruchirappalli**, **Tamil Nadu-620015**, through Registered/ Speed Post with "Application for Junior Research Fellow ISRO" mentioned on the cover:
 - Filled in application should be furnished in the prescribed format with Self-attested copies of marksheets, degree certificates and experience certificates.
- C. The duly filled-in hard copy of the application along with copies of certificates should reach us before 5 pm on 27th May 2022 in prescribed format.
- D. The soft copy of the application should be sent to *isrobcdr@gmail.com* on or before 22nd May 2022.
- E. The shortlisted candidates will be intimated about the interview through e-mail. The interview will beheld in EEE department, NIT Tiruchirappalli for the shortlisted candidates.
- F. Candidates shall bring along with them the original certificates at the time of interview for verification.
- G. Please note that No TA/DA is admissible for attending the interview.
- H. The decision of the selection committee is final. Canvassing in any form leads to rejection of the candidature.

Dr.Shelas Sathyan

FORM No. 8

OFFICE OF THE DEAN (R & C), NIT, TIRUCHI RECRUITMENT OF TEMPORARY PROJECT STAFF --PRESCRIBED APPLICATION FOR THE POST OF JRF

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Signatu	re of the Applic	ation Screening	Committee Chairm	an	
		APPLICATION I	FOR THE POST OF J	RF	
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3. Mother Tongue					
4. Date of Birth			Date	Month	Year
5. Sex			Male / Female		
6. Marital Status			Married / Single		
7. Category	SC / ST / OBC	/ General	Please specify		
8. Address for com	munication wit	h Mobile			
number and E Mai	lID				
9. Project Title					
10. Name of the Po	ost applied for				
11. Advertisement	Number with D	ate			
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showing the perce	ntage of marks	or CGPF from HS	SC onwards		
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6616	University	University	of study		GCPA
S.S.L.C					
H.S.C					
Graduation					
Post-Graduation					
Any other					
Enclose self-attest	ed Xerox copies		1		1
12. GATE Score		Subject			
	Year				
13. NET Score					
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14. Work Experience, if any

Organization	Designation		Duration			Nature	Nature of Job	
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14. Previous Rese	arch work and pu	blication	n, if any (enc	lose cop	oies of p	oublished	d or unpu	blished work)
15. Proof of past s	study as a sponsor	red cand	lidate, or otl	ner cont	ractual	obligati	on, if any	:
16. Reference								
Name		Address	5			Phone	& E Mail	ID
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